## NSN 5961-01-298-8198

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View Online at https://aerobasegroup.com/nsn/5961-01-298-8198 **Inclosure Material:** Metal **Overall Length:** 92.0 millimeters **Overall Height:** 10.0 millimeters **Overall Width:** 92.0 millimeters **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 gate non-trigger voltage, dc and 600.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 20.00 microamperes forward current, total rms **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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